Ordering number : ENA1062A

2SC5226A

RF Transistor
10V, 70mA, fT=7GHz, NPN Single MCP

ON Semiconductor®
http://onsemi.com

Features

- Low-noise : NF=1.0dB typ (f=1GHz)
- High gain : $|S21e|^2$=12dB typ (f=1GHz)
- High cut-off frequency : f_T=7GHz typ

Specifications

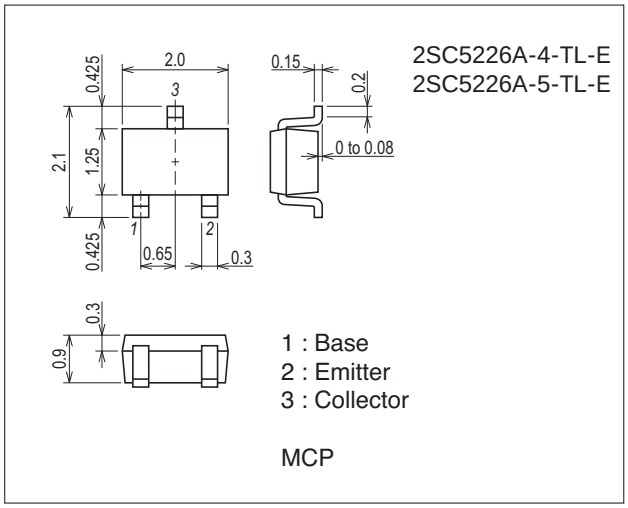
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		20	V
Collector-to-Emitter Voltage	V_{CEO}		10	V
Emitter-to-Base Voltage	V_{EBO}		2	V
Collector Current	I_C		70	mA
Collector Dissipation	P_C		150	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		−55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

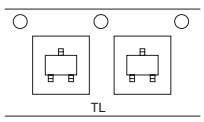
unit : mm (typ)
7023A-009



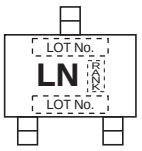
Product & Package Information

- Package : MCP
- JEITA, JEDEC : SC-70, SOT-323
- Minimum Packing Quantity : 3,000 pcs./reel

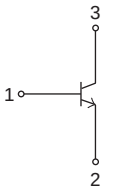
Packing Type: TL



Marking



Electrical Connection



Electrical Characteristics at Ta=25°C

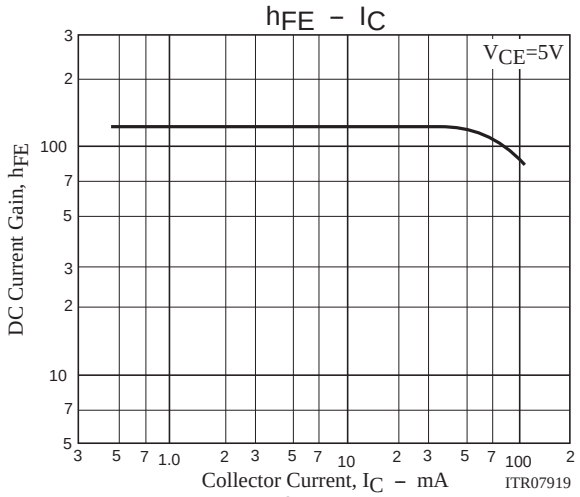
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	V_{CB}=10V, I_E=0A			1.0	μA
Emitter Cutoff Current	I_{EBO}	V_{EB}=1V, I_C=0A			10	μA
DC Current Gain	h_{FE}	V_{CE}=5V, I_C=20mA	60*		270*	
Gain-Bandwidth Product	f_T	V_{CE}=5V, I_C=20mA	5	7		GHz
Output Capacitance	Cob	V_{CB}=10V, f=1MHz		0.75	1.2	pF
Reverse Transfer Capacitance	Cre			0.5		pF
Forward Transfer Gain	$|S21e|^2$1	V_{CE}=5V, I_C=20mA, f=1GHz	9	12		dB
	$|S21e|^2$2	V_{CE}=2V, I_C=3mA, f=1GHz		8		dB
Noise Figure	NF	V_{CE}=5V, I_C=7mA, f=1GHz		1.0	1.8	dB

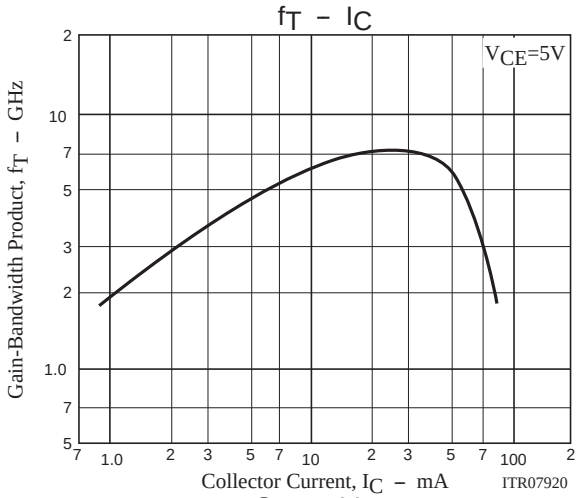
* : The 2SC5226A is classified by 20mA hFE as follows :

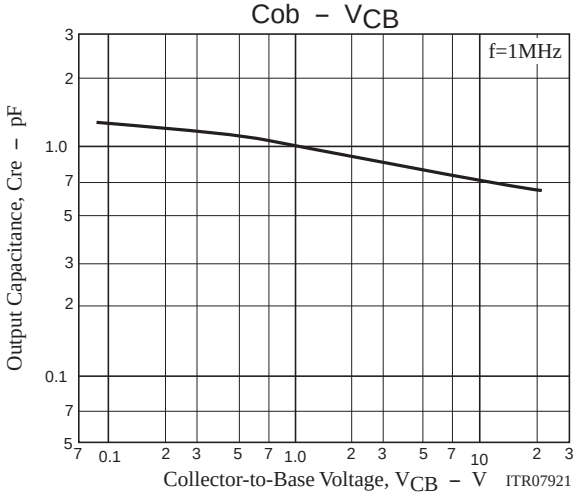
Rank	3	4	5
h_{FE}	60 to 120	90 to 180	135 to 270

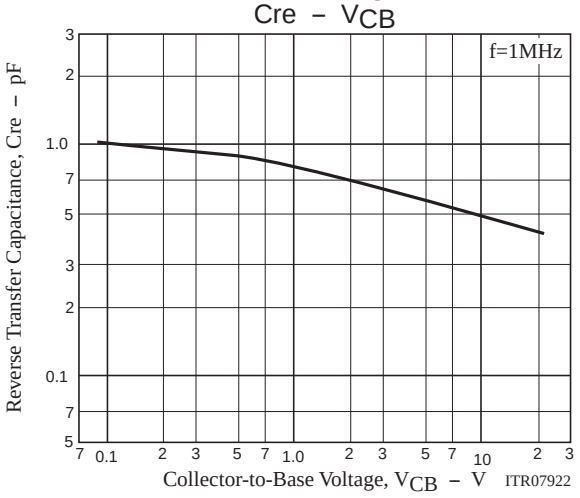
Ordering Information

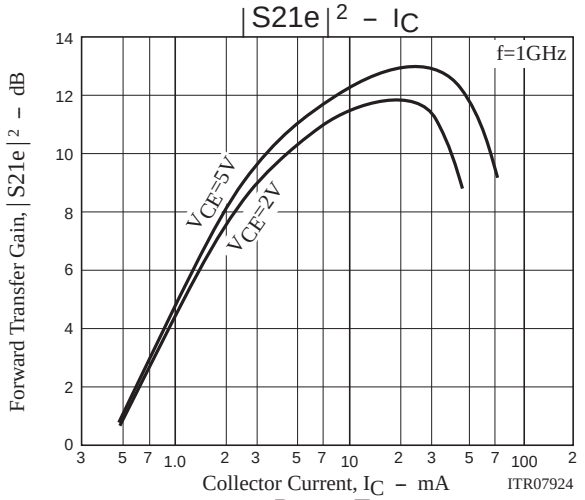
Device	Package	Shipping	memo
2SC5226A-4-TL-E	MCP	3,000pcs./reel	Pb Free
2SC5226A-5-TL-E	MCP	3,000pcs./reel	

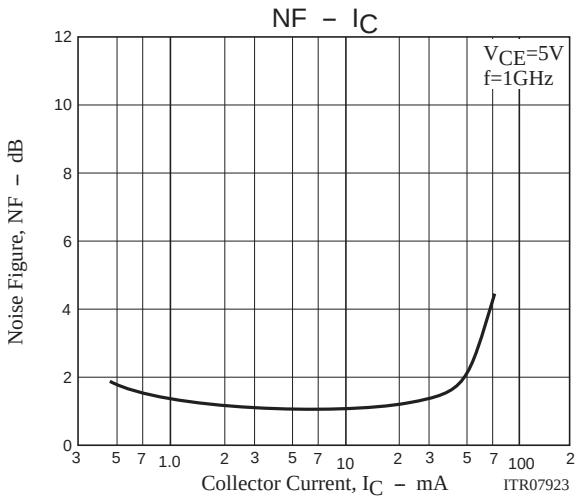


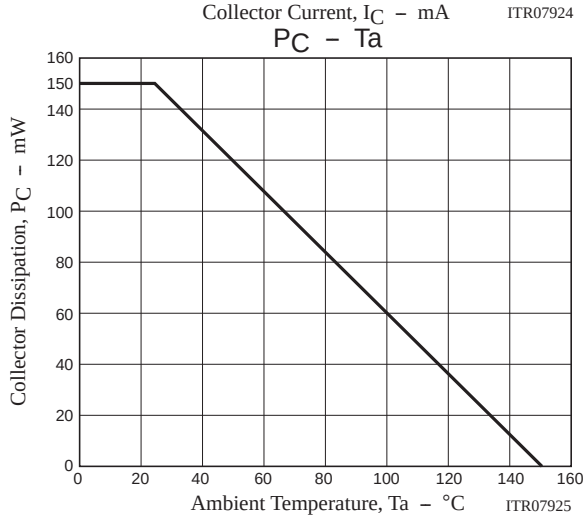




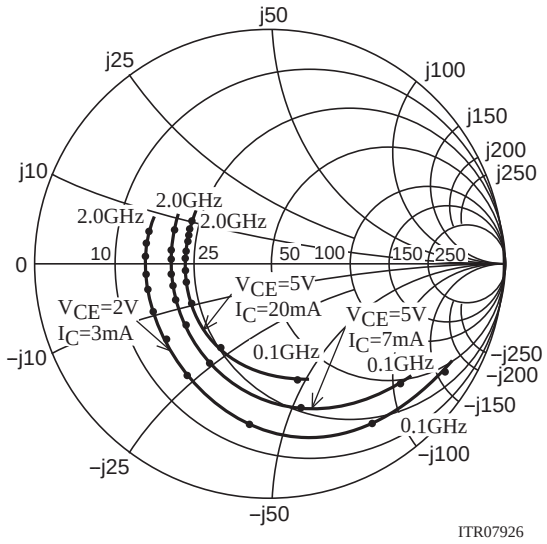



|S21e|² – IC
f=1GHz
VCE=5V
VCE=2V
Forward Transfer Gain, |S21e|² – dB
Collector Current, IC – mA
ITR07924

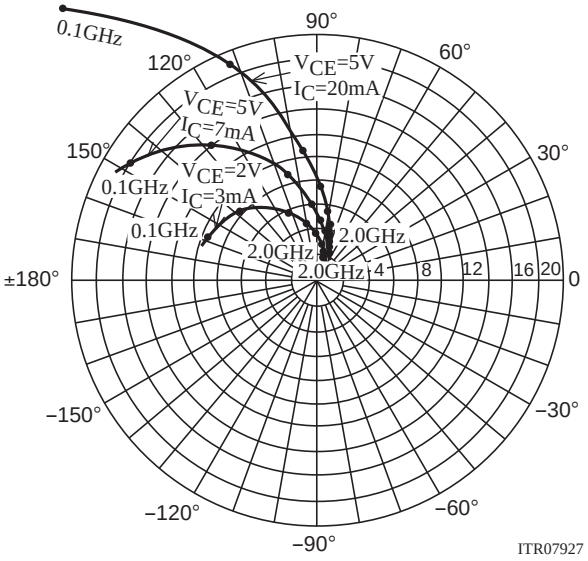

NF – IC
VCE=5V
f=1GHz
Noise Figure, NF – dB
Collector Current, IC – mA
ITR07923


PC – Ta
Collector Dissipation, PC – mW
Ambient Temperature, Ta – °C
ITR07925

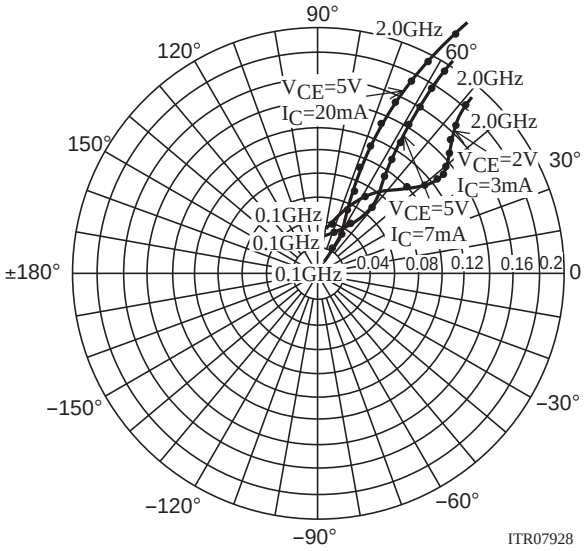
f=100MHz, 200MHz to 2000MHz(200MHz Step)



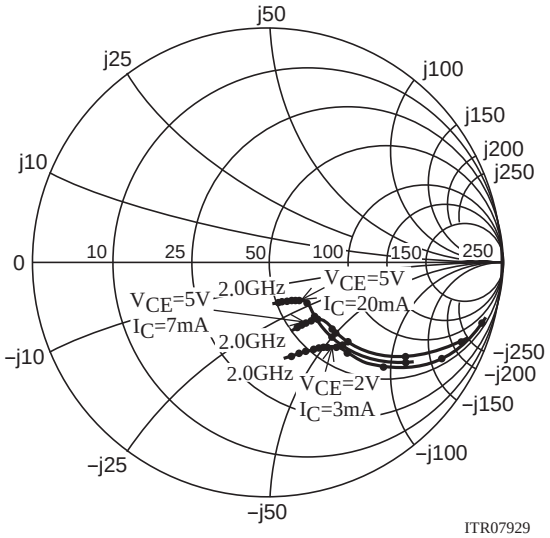
f=100MHz, 200MHz to 2000MHz(200MHz Step)



f=100MHz, 200MHz to 2000MHz(200MHz Step)



f=100MHz, 200MHz to 2000MHz(200MHz Step)



S Parameters (Common emitter)

V_{CE}=5V, I_C=7mA, Z_O=50Ω

Freq(MHz)	|S11|	∠S11	|S21|	∠S21	|S12|	∠S12	|S22|	∠S22
100	0.720	-46.0	17.973	148.5	0.030	68.5	0.880	-23.6
200	0.612	-80.9	13.927	127.3	0.047	57.1	0.697	-37.6
400	0.497	-121.3	8.656	105.0	0.066	51.3	0.479	-47.6
600	0.456	-143.5	6.080	92.8	0.079	52.9	0.382	-50.5
800	0.440	-157.6	4.725	84.3	0.094	55.4	0.339	-51.8
1000	0.436	-167.5	3.864	77.0	0.110	56.8	0.323	-53.4
1200	0.434	-176.1	3.258	70.3	0.126	57.9	0.312	-55.8
1400	0.433	176.6	2.847	64.5	0.143	58.4	0.304	-58.3
1600	0.433	170.9	2.329	57.4	0.160	58.9	0.296	-62.0
1800	0.434	165.0	2.252	54.2	0.178	58.6	0.293	-65.0
2000	0.439	159.6	2.057	49.2	0.197	58.1	0.294	-68.1

V_{CE}=5V, I_C=20mA, Z_O=50Ω

Freq(MHz)	|S11|	∠S11	|S21|	∠S21	|S12|	∠S12	|S22|	∠S22
100	0.481	-78.8	29.795	132.9	0.022	63.9	0.707	-38.2
200	0.420	-119.2	19.008	112.2	0.033	60.8	0.470	-51.1
400	0.391	-151.6	10.416	95.4	0.052	64.7	0.296	-55.3
600	0.386	-166.4	7.084	86.6	0.071	67.2	0.236	-56.1
800	0.381	-175.9	5.407	80.1	0.092	68.4	0.213	-56.6
1000	0.382	178.2	4.401	74.1	0.114	67.8	0.208	-57.9
1200	0.385	172.1	3.701	68.5	0.134	66.8	0.204	-60.7
1400	0.388	166.7	3.217	63.6	0.156	65.6	0.202	-63.5
1600	0.390	162.1	2.839	58.8	0.176	64.0	0.199	-67.9
1800	0.391	156.7	2.534	54.3	0.197	62.4	0.197	-71.2
2000	0.394	152.1	2.319	50.1	0.219	60.6	0.197	-74.2

V_{CE}=2V, I_C=3mA, Z_O=50Ω

Freq(MHz)	|S11|	∠S11	|S21|	∠S21	|S12|	∠S12	|S22|	∠S22
100	0.858	-32.4	9.413	157.2	0.040	72.6	0.945	-16.5
200	0.782	-60.7	8.187	138.5	0.070	59.2	0.833	-29.3
400	0.653	-101.1	5.855	113.8	0.101	44.5	0.637	-43.2
600	0.588	-126.5	4.337	98.4	0.114	39.1	0.515	-50.0
800	0.557	-143.7	3.444	87.7	0.122	38.0	0.454	-53.8
1000	0.543	-156.3	2.871	78.5	0.130	38.6	0.426	-57.1
1200	0.536	-166.8	2.446	70.5	0.137	40.3	0.407	-60.3
1400	0.533	-175.5	2.145	63.5	0.146	42.5	0.393	-63.8
1600	0.527	177.0	1.904	57.1	0.155	45.0	0.382	-68.0
1800	0.525	170.3	1.714	51.7	0.168	47.3	0.379	-72.0
2000	0.528	163.8	1.564	45.9	0.183	49.2	0.378	-75.8

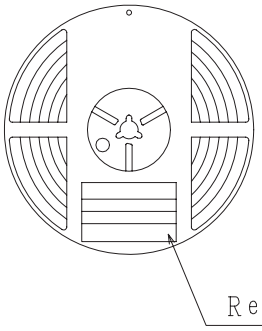
Embossed Taping Specification

2SC5226A-4-TL-E, 2SC5226A-5-TL-E

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
MCP	MCP	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

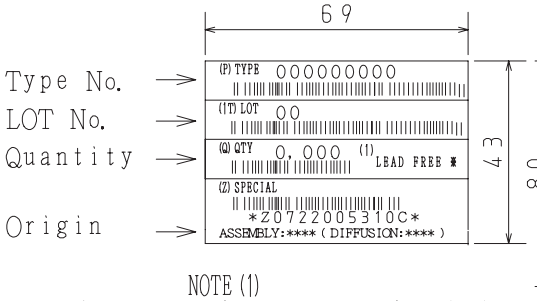
Packing method



Reel label

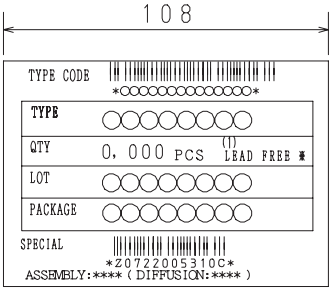
Reel label, Inner box label

(unit:mm)



Outer box label

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



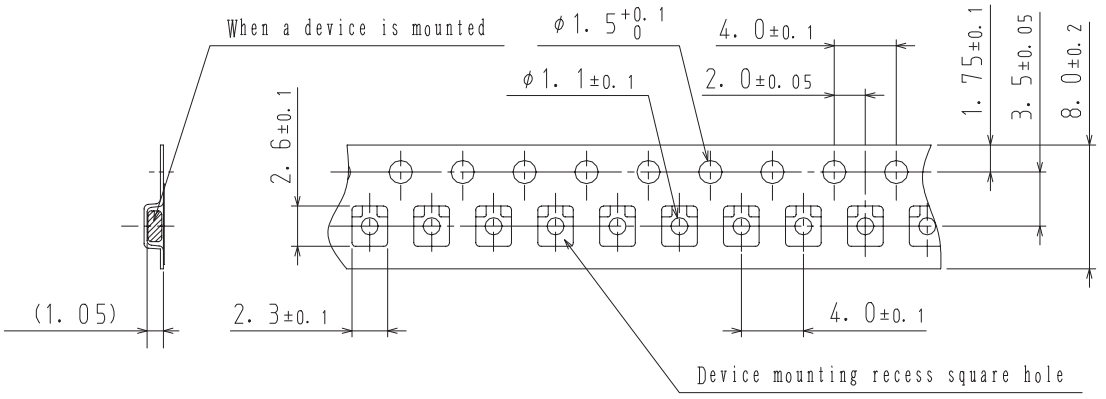
NOTE (1)

The LEAD FREE ※ description shows that the surface treatment of the terminal is lead free.

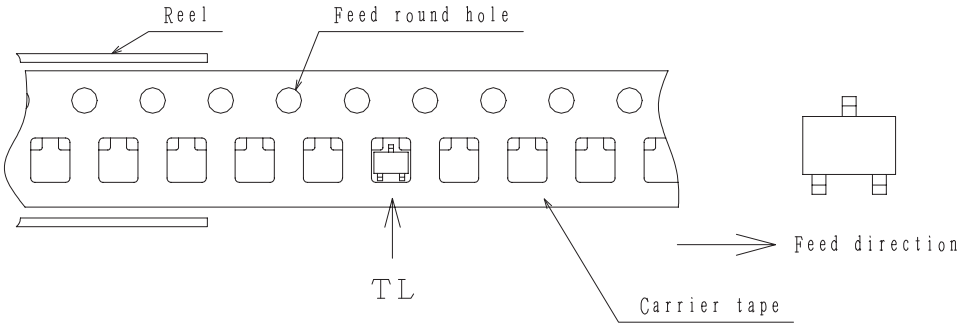
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



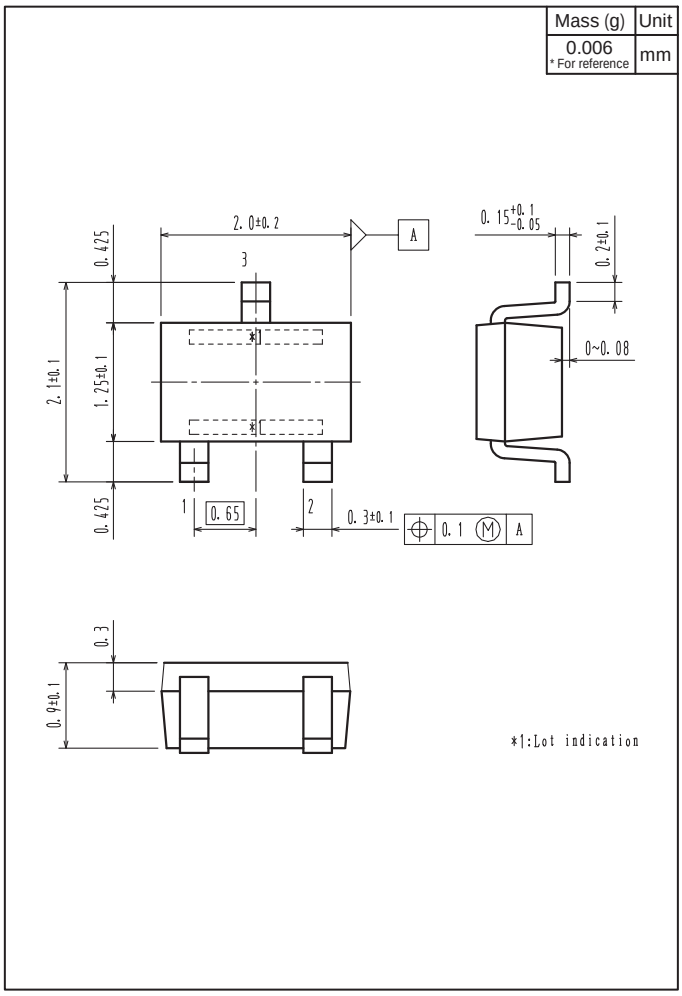
2-2. Device placement direction



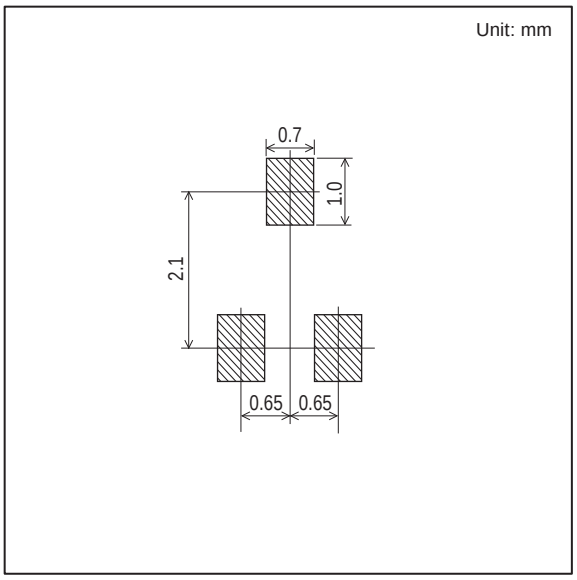
Those with oen electrode terminal on the feed hole side·····TL

Outline Drawing

2SC5226A-4-TL-E, 2SC5226A-5-TL-E



Land Pattern Example



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